

Technical Support of Power Stack for LV100 Modules

Merit of Technical Support with Power Stack

By receiving stack support, you will have the following benefits:

- ① **Achieving a power converter with 2MW of output power**
- ② **Significantly shortening the development period**
- ③ **Improving the difficulty of component selection**

Mitsubishi Electric has prepared reference information for inverter design when using IGBT module with LV100 package. When developing the prototype inverter (Power Stack) described in this material, we took into consideration as follow:

- Relationship between temperature of parallel power modules and pitch distance
- Electrical and thermal design for DC and AC busbar with considering temperature rising and skin effect
- Current balance
- Short circuit protection.

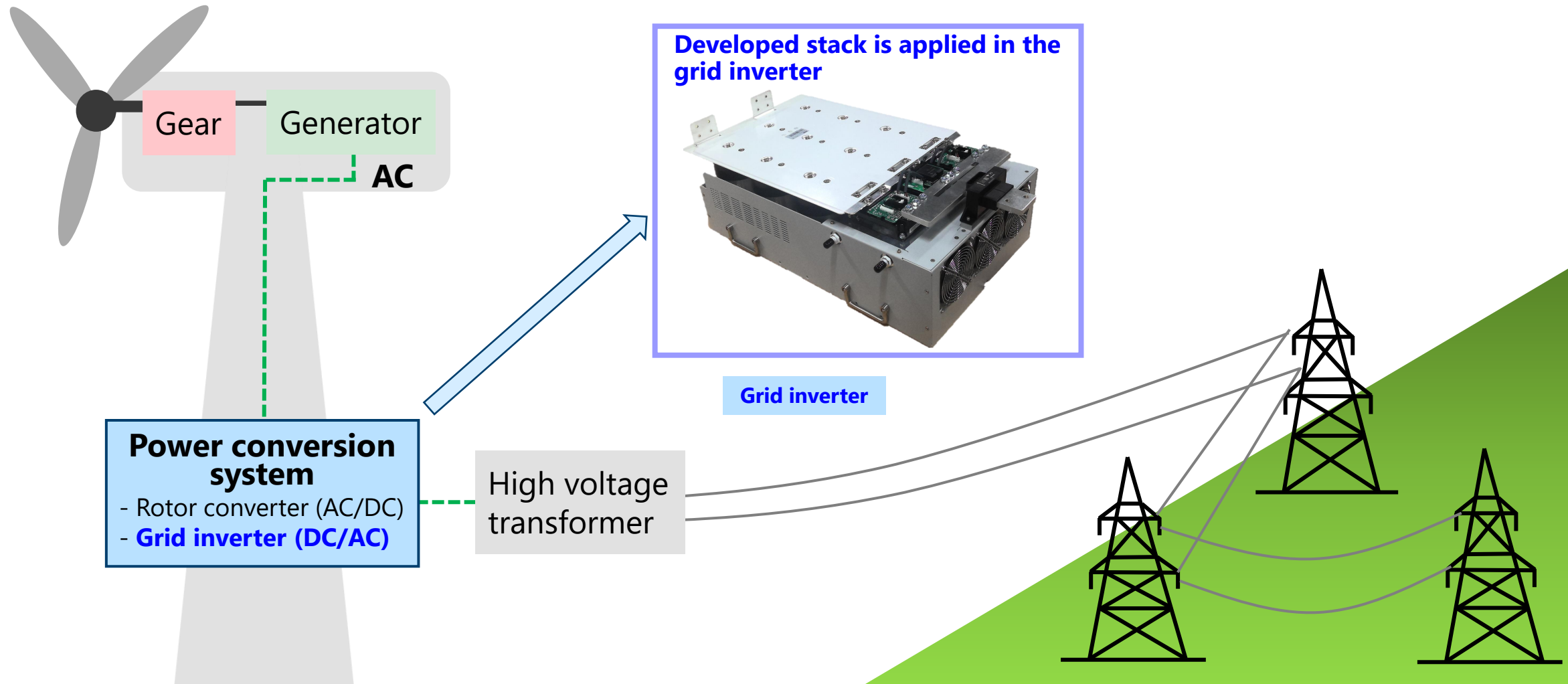
We expect that by user could reduce their developed period in system design by referring to these reference data, hence please contact us to obtain more information.

Introduction of Power Stack

Application: Renewable Energy (Ex: wind power)

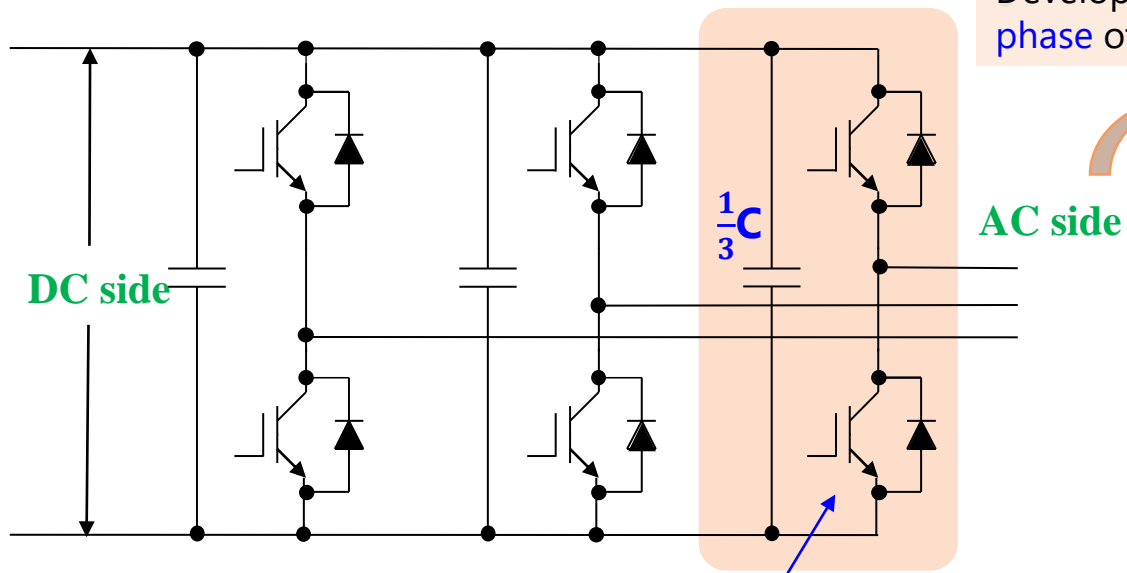
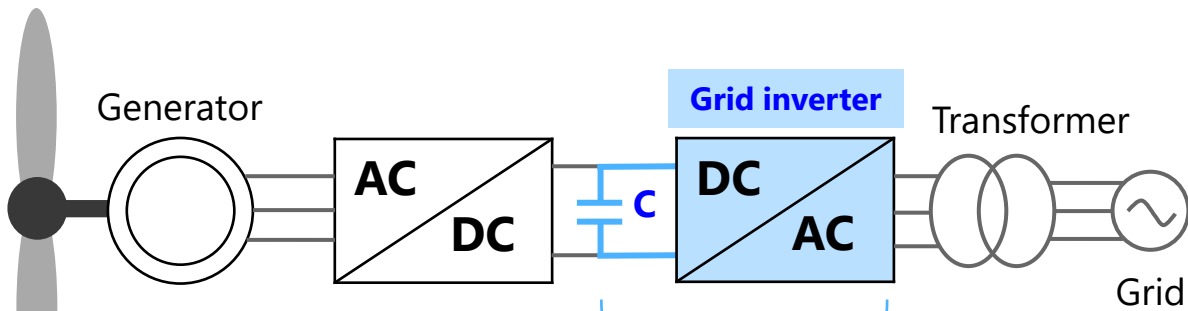
A power conversion system is equipped with power modules and lots of components.

→ **Much knowhow is required other than power modules**



What Is Power Stack?

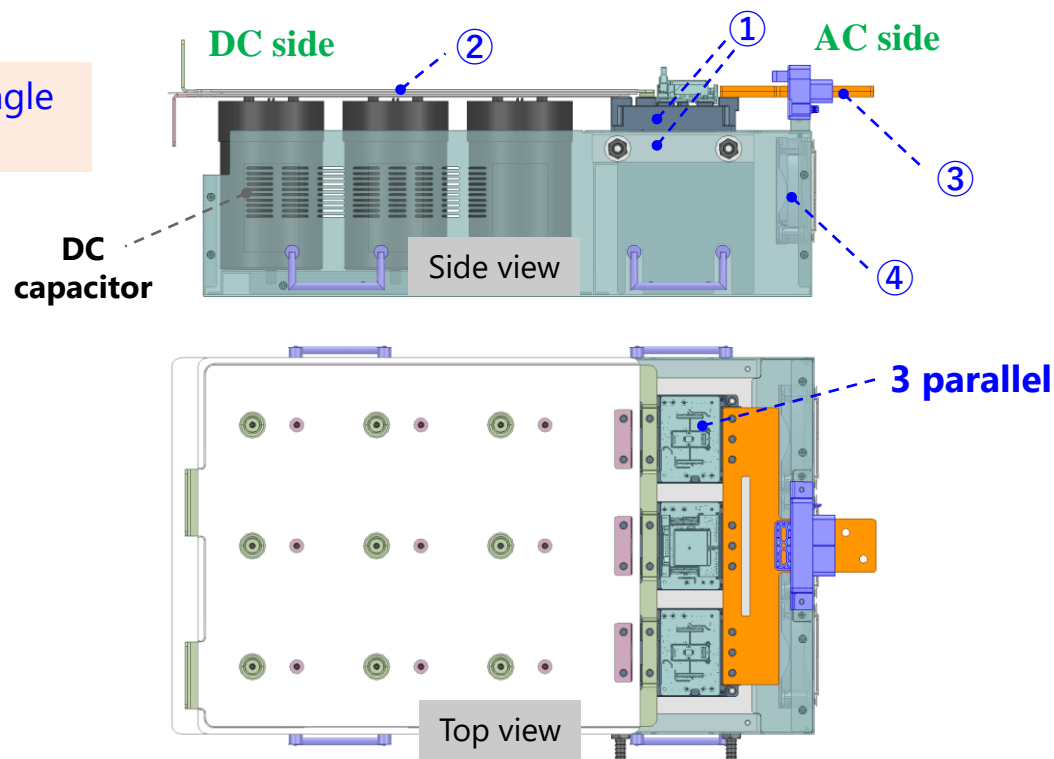
Stack definition: Things that collect and assemble components
→ Power modules + peripheral components



Use 2 in 1 IGBT module → CM1200DW-34T (1.7kV/1200A)

Specification decision : 2MW → 690Vac / about 1800A_{rms}

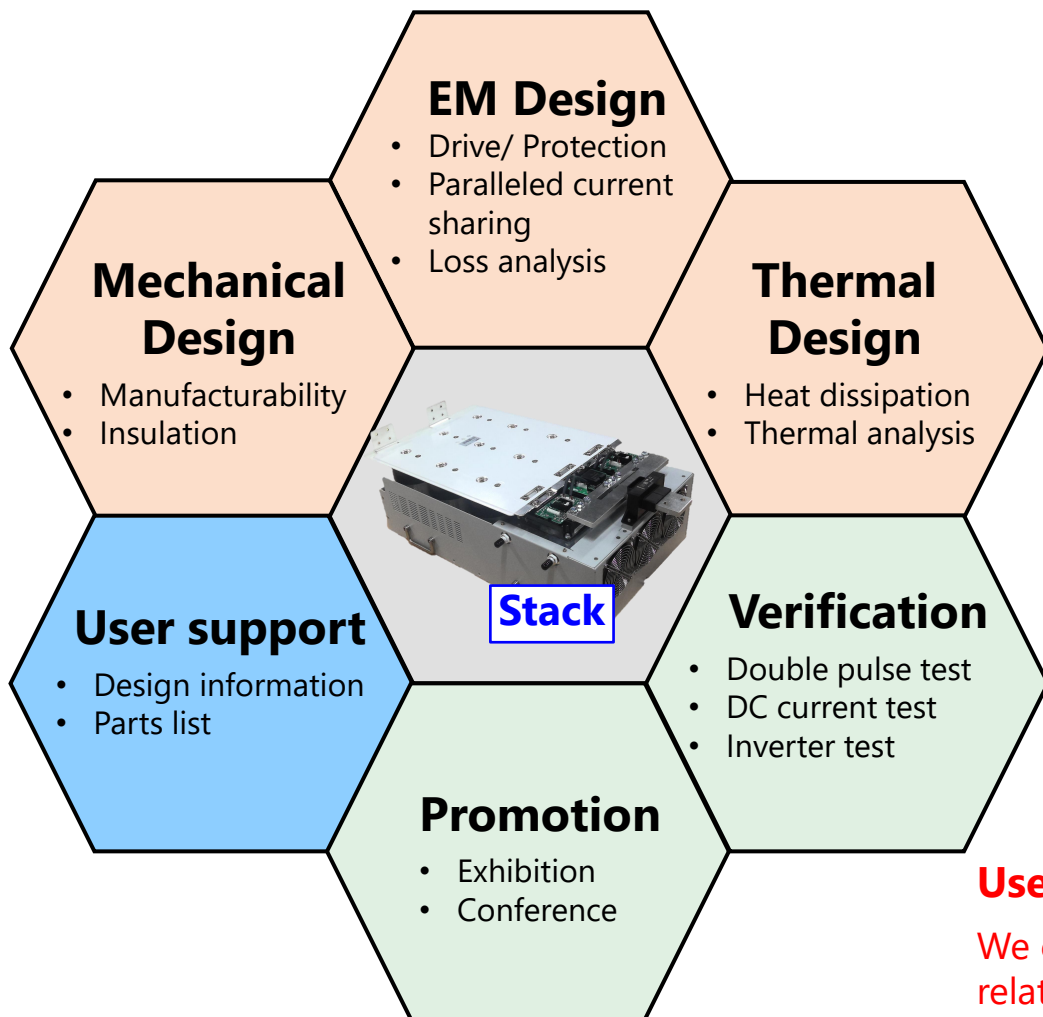
- ① Selection of IGBT module and heatsink
 - Parallel number of IGBT modules (3-parallel)
 - Cooling ability of heatsink (Liquid/ Air)
 - Placement of IGBT module (Pitch distance between modules with considering thermal interface)
- ② Thermal design of DC laminated busbar
- ③ Thermal and current balance design of AC busbar
- ④ Comparison of NTC temperature under different cooling method.



Target of Developing a Stack with Power Module

User's perspective : We want to improve the accuracy of the prototype because it requires a lot of know-how to develop the stack with using power modules, also it takes time, money and effort to design, trial manufacture and evaluate.

⇒ **The proposal, design and verification data of 「total solution」 provided by device manufacturer is requested.**



Mitsubishi Electric

- R&D and manufacture of power device
- Product promotion

User

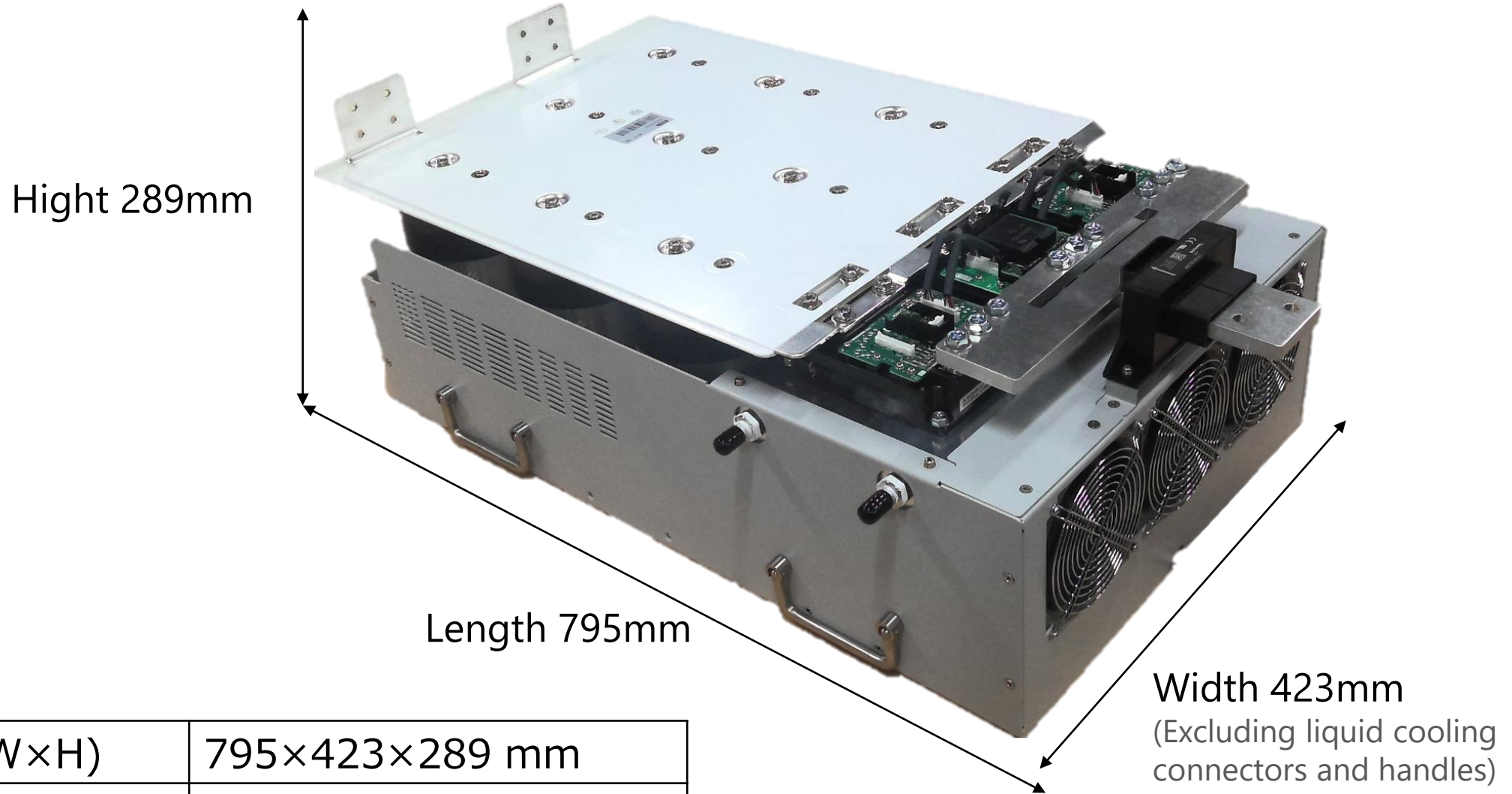
- Investigation of system specification
- Prototype design
- Trial manufacture
- Prototype verification (operated performance)
- Reliability evaluation (long-term performance)
- Order decision

User support by stack

We can support User R&D by providing stack-related information prepared in advance.

→ **Reduction of User's development time**

Stack Geometry and Weight



| | |
|--------------|----------------|
| Size (L×W×H) | 795×423×289 mm |
| Weight | About 65 kg |

Specification of Stack, and Technical Points

Specification of Stack

| Item | Specification |
|------------------|--------------------|
| Topology | 2 level |
| Size (L × W × H) | 795 × 423 × 289 mm |
| Weight | About 65 kg |
| Output power | 2 MW |
| DC Voltage | 1100 V |
| Current | AC : 1800 Arms |
| Current balance | Within 5% |

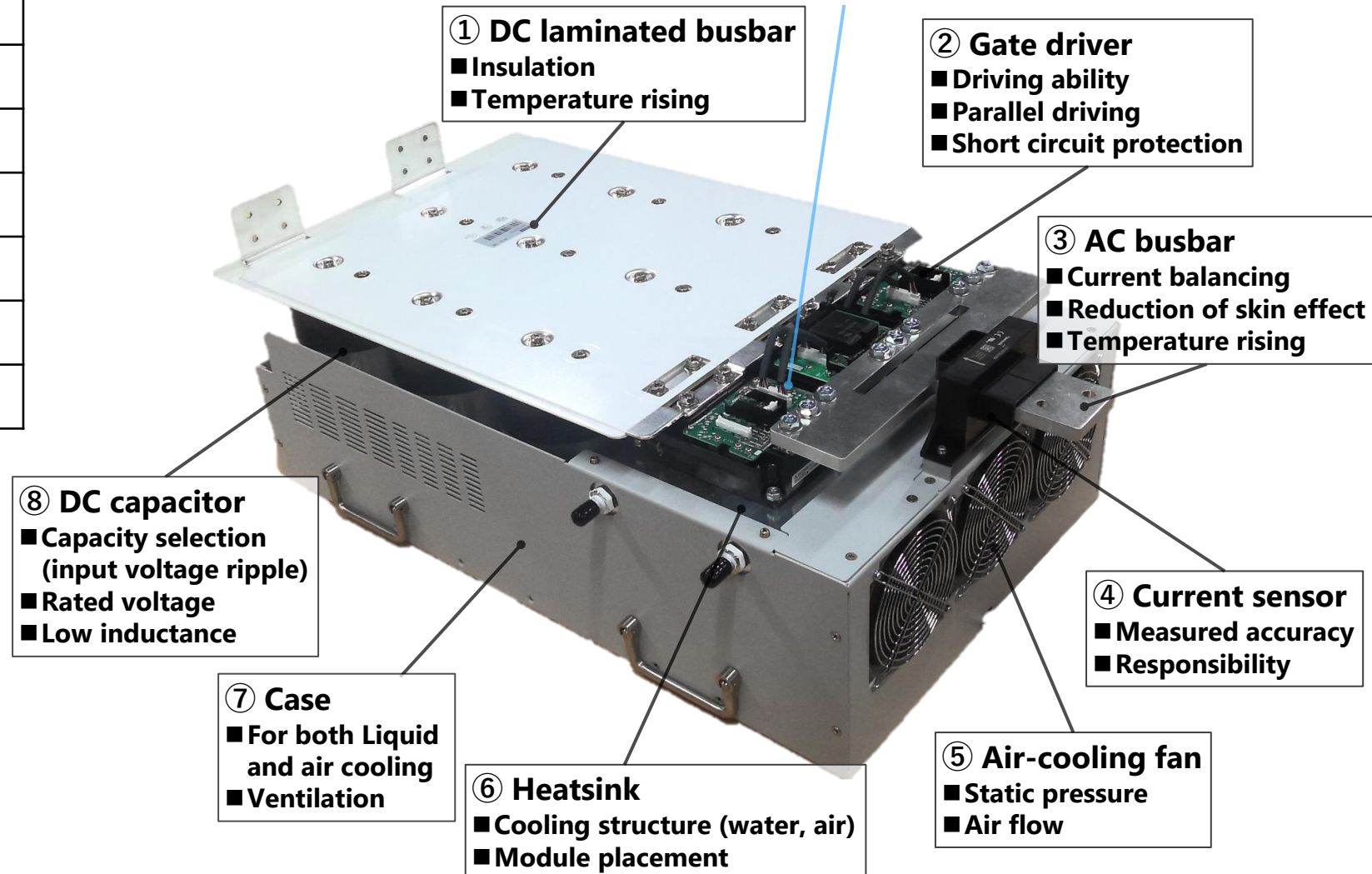
Remarks

- Thermal was verified by DC current evaluation and CAE.
- Current balance was verified by CAE and DPT.
*DPT=Double Pulse Test
- Short Circuit protection was verified by pulse test.

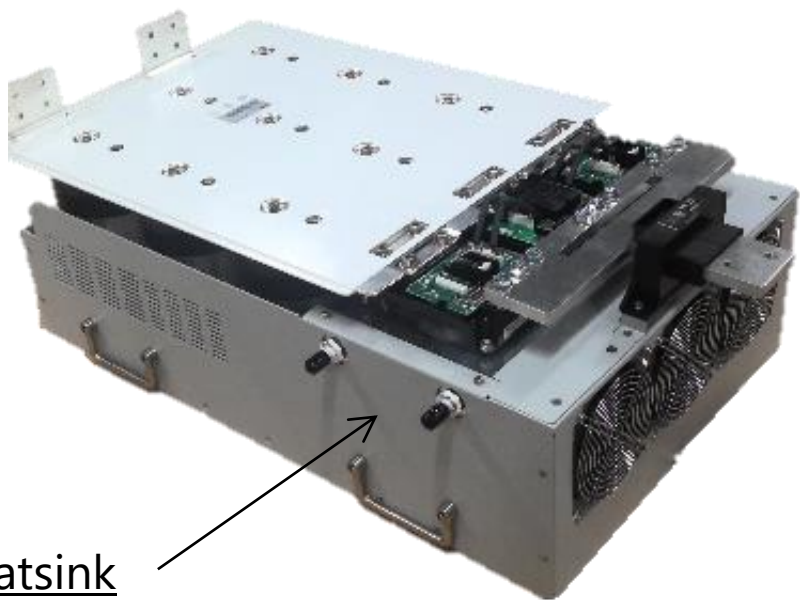
It can help technical support even if spec. is not just fit to your target.

Technical points

•IGBT modules: **CM1200DW-34T×3-parallel, LV100 series, made by Mitsubishi Electric**



Evaluated Results of Maximum Output Power of Inverter

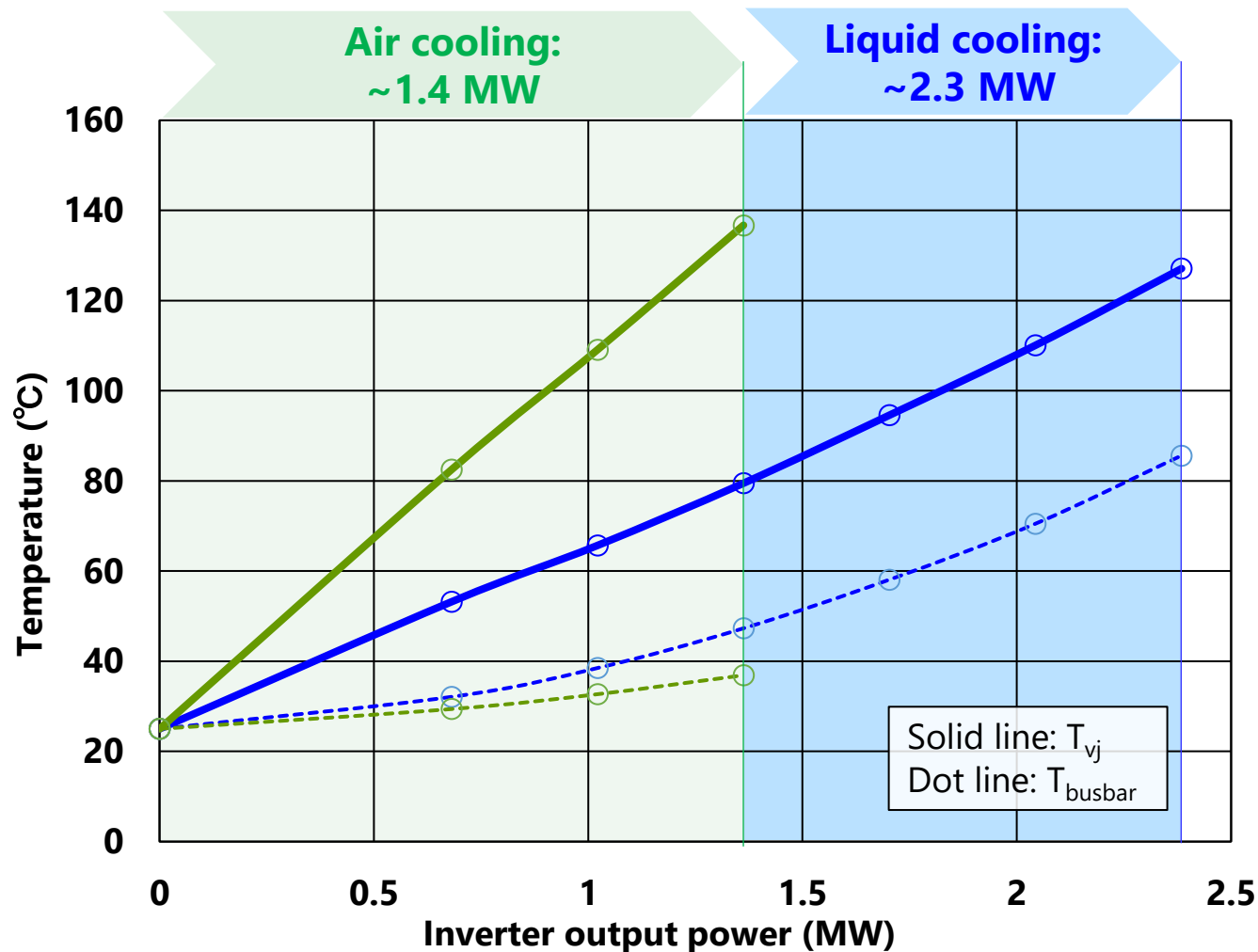
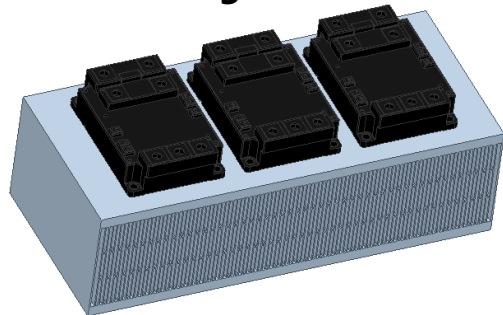
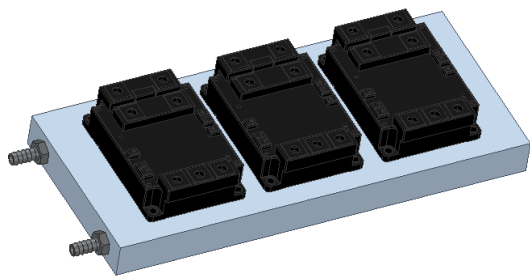


Heatsink

User can select liquid cooling or air cooling

Liquid cooling heatsink

Air cooling heatsink



Note
-Output characteristic is evaluated under 25°C of ambient and water inlet temperature
-Heat generating of DC capacitors is not considered

※The maximum output capacity under 3-phase inverter operation is derived by thermal evaluation result of single phase

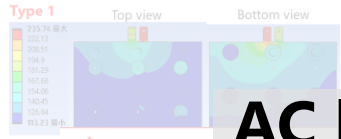
Technical Point of Power Stack

Please contact us to obtain detail design material.

DC busbar design

Design target: DC busbar temperature $T_{busbar-DC} \leq 105^{\circ}\text{C}$

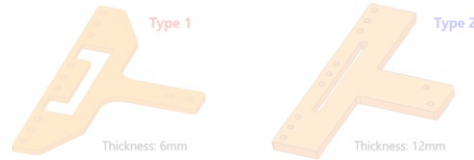
| Item | Spec. | Note |
|--------------------|--------------|-------------------------------------|
| System voltage | <1000Vac | |
| Insulation voltage | 3400V | EN50178 standard |
| Partial discharge | 1220V <10pC | |
| Material | Copper | C1100 |
| Altitude | Max. : 2000m | |
| Pollution level | 2 | |
| Rated current | 1800 Arms | Ta = 50°C |
| Temp. limitation | Max.: 85°C | - Limited by DC cap. - Ta = 50°C |



AC busbar design

Design target: ① AC busbar temperature $T_{busbar-AC} \leq 105^{\circ}\text{C}$
② Current imbalance $\leq 5\%$

| Item | Spec. | Note |
|------------------|-------------|-----------|
| Rated current | 1800 A | Ta = 50°C |
| Temp. limitation | Max.: 105°C | |

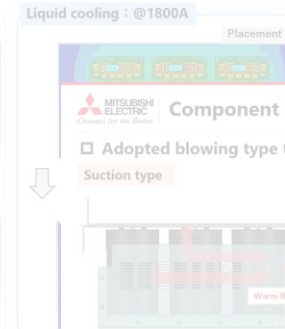
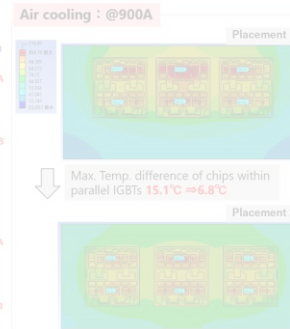


The current balance and heat generation of the busbar are optimized with considering the thickness and shape, current balance and skin effect.

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Module placement and Heatsink selection

Design target: ① Symmetric area of heat dissipation for Tr1 and Tr2
② Distance placement between parallel IGBTs



Component and NTC temperature under different cooling condition





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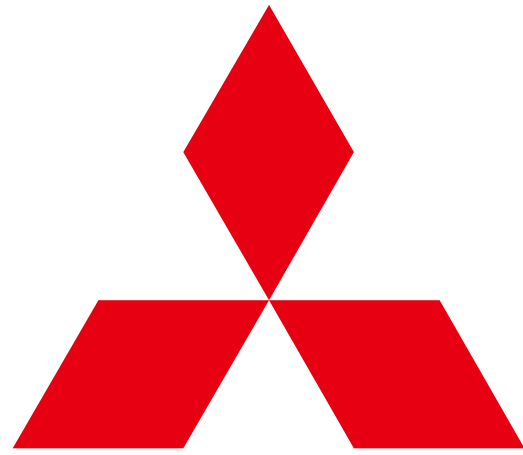
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LV100 & HV100 by Mitsubishi Electric Corporation

Standardized package / footprint for various voltage and current ratings

| Main target | On-shore WP | | | Off-shore WP | | | |
|---------------------|--|---------------|--------|--|--|--|-------|
| Line-up |  LV100 (Industrial) | | |  LV100 (HVIGBT) | |  HV100 (HVIGBT) | |
| Application | Renewable, Industrial, Others | | | Traction, Power transmission | | Traction, Power transmission | |
| Footprint | 100mm × 140mm × 40mm | | | 100mm × 140mm × 40mm | | 100mm × 140mm × 40mm | |
| V_{isol} | 4kVrms | | | 6kVrms | | 10kVrms | |
| Rated Voltage | 1.2 kV | 1.7 kV | 2.0 kV | 1.7 kV | 3.3 kV | 3.3 kV | 4.5kV |
| Rated Current Si | 800A 1200A | 800A 1200A | 1200A | 1200A | 450A 600A | 450A 600A | 450A |
| Hybrid SiC | - | - | - | 1200A | 600A | - | - |
| Full SiC | - | - | - | - | 2 nd chip 185A 375A 750A | 3 rd chip 200A 400A 800A | - |

LV100, HV100: New standard package in high power industrial application



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